

DMTH12H007SPSWQ 120V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI5060-8

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Product Summary

BV _{DSS}	Rds(on) Max	I _D Tc = +25°C (Note 10)
120V	8.9mΩ @ V _{GS} = 10V	84A
	16mΩ @ V _{GS} = 6V	70A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Switching
- DC-DC converters

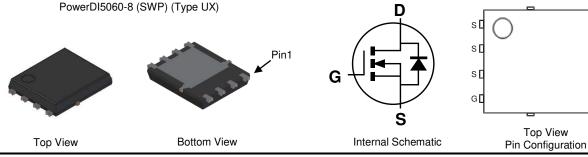
Features and Benefits

- Rated to $+175^{\circ}C$ Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- <1.1mm Package Profile Ideal for Thin Applications</p>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMTH12H007SPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Pookogo	Packing		
Part Number	Package	Qty.	Carrier	
DMTH12H007SPSWQ-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	

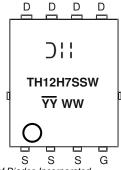
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	120	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	Tc = +25°C (Note 10) Tc = +100°C	ID	84 60	А
Pulsed Drain Current (10µs Pulse, T _C = +25°C, Package Limited)		Ідм	336	А
Continuous Body Diode Forward Current (Note 6) T _C = +25°C		ls	84	А
Pulsed Body Diode Current (10µs Pulse, T _C = +25°C, Package Limited) T _C = +25°C		lsм	336	А
Avalanche Current, L = 3mH (Note 9)	I _{AS}	15.5	А	
Avalanche Energy, L = 3mH (Note 9)		Eas	360.4	mJ

Thermal Characteristics

Characteristic	Symbol	Value (Typ.)	Unit
Total Power Dissipation (Note 5)	PD	3.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	43	°C/W
Total Power Dissipation (Note 6)	PD	125	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	1.2	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C

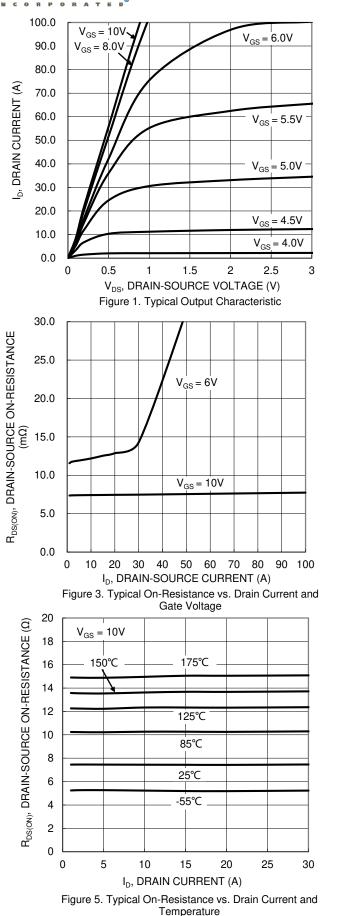
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

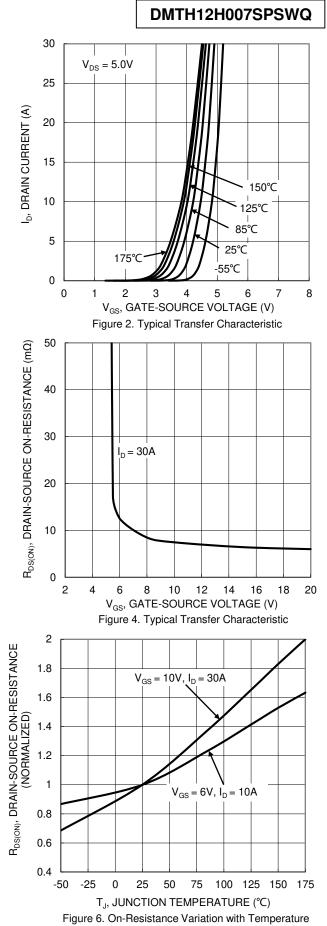
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	120	_		V	$V_{GS} = 0V$, $I_D = 10mA$
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 96V, V_{GS} = 0V$
Gate-Source Leakage	IGSS		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						-
Gate Threshold Voltage	VGS(TH)	2	—	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance		_	7.5	8.9	mΩ	V _{GS} = 10V, I _D = 30A
Static Drain-Source On-Resistance	Rds(on)	_	12	16	11122	V _{GS} = 6V, I _D = 10A
Diode Forward Voltage	V _{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 30A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	3142	_	pF	$V_{DS} = 60V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss		665			
Reverse Transfer Capacitance	Crss		29			
Gate Resistance	R _G		1.9		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = 10V)	Qg		44			
Gate-Source Charge	Qgs		15		nC	VDS = 60V, ID = 25A
Gate-Drain Charge	Qgd		9			
Turn-On Delay Time	tD(ON)		12.5			$V_{DD} = 60V, V_{GS} = 10V,$
Turn-On Rise Time	t _R		13.7		ns	
Turn-Off Delay Time	tD(OFF)	_	24.4	_		$I_{D} = 25A, R_{G} = 2.7\Omega$
Turn-Off Fall Time	tF	_	10.9	—		
Reverse Recovery Time	trr	_	55	_	ns	
Reverse Recovery Charge	QRR		105	_	nC	IF = 25A, di/dt = 100A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 10. Package limited.

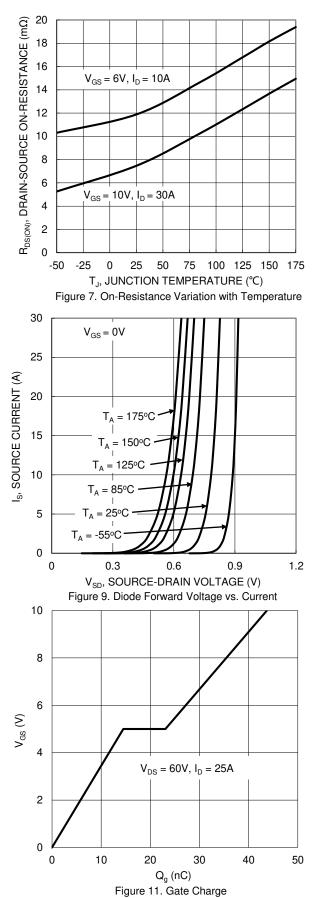


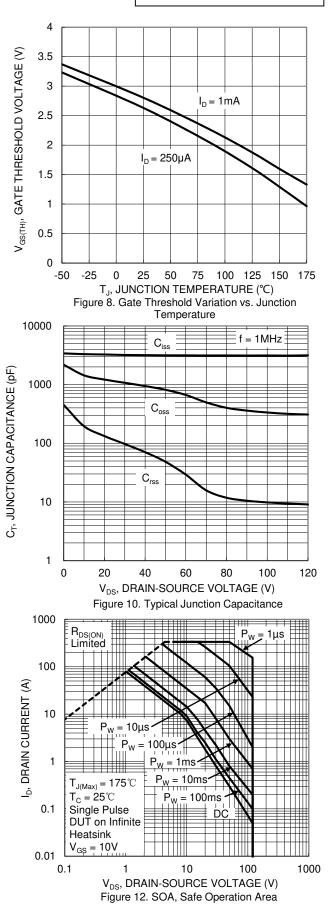






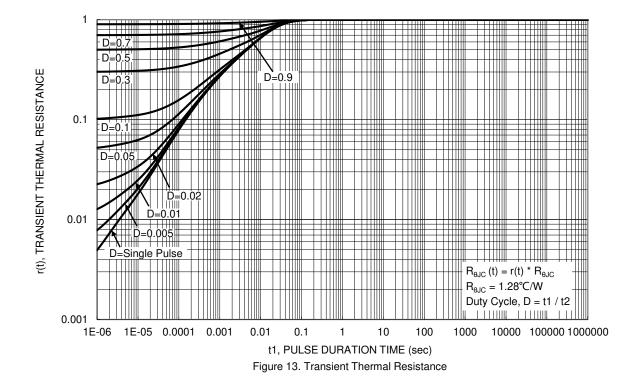
DMTH12H007SPSWQ





DMTH12H007SPSWQ Document number: DS44558 Rev. 2 - 2







PowerDI5060-8 (SWP) (Type UX)

Мах

1.10

0.05

0.50

0.35

Тур

1.00

0.41

0.25

Min

0.90

0

0.30

0.20

Dim

Α

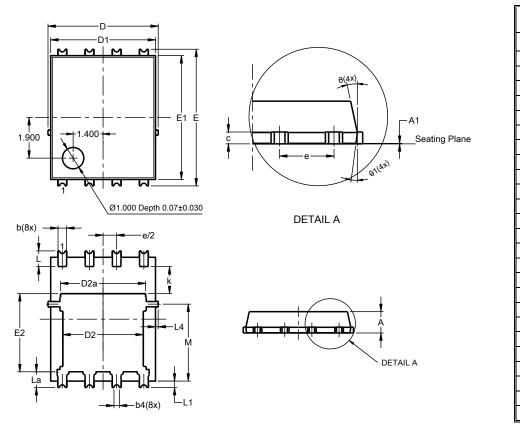
A1

b

b2

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

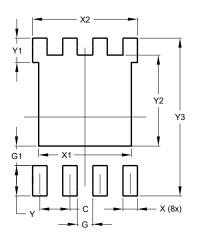


PowerDI5060-8 (SWP) (Type UX)

b4	0.25REF				
С	0.230	0.330	0.277		
D	5.15 BSC				
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
Е	6.40 BSC				
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1.27BSC				
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0.050REF				
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8 (SWP) (Type UX)

Dimensions	Value		
Dimensions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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